NSN 5961-01-362-8403

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-362-8403 **Inclosure Material:** Glass and metal **Overall Length:** 3.681 inches **Overall Height:** 1.181 inches **Overall Width:** 1.024 inches **Function For Which Designed:** Switching **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Unthreaded hole Voltage Rating In Volts Per Characteristic: 1200.0 repetitive peak off-state voltage all semiconductor and 1350.0 nonrepetitive peak off-state voltage all semiconductor and 960.0 off-state voltage, dc all semiconductor and 1200.0 repetitive peak reverse voltage all semiconductor and 1350.0 nonrepetitive peak reverse voltage all semiconductor and 960.0 reverse voltage, instantaneous all semiconductor and 10.0 gate voltage, dc all semiconductor **Current Rating Per Characteristic:** 86.00 amperes drain current pascal all semiconductor and 1100.00 amperes forward current, dc nanoamperes all semiconductor and 2.00 amperes base current, dc horsepower metric all semiconductor **Power Rating Per Characteristic:** 0.5 watts any acceptable universal all semiconductor and 5.0 watts any acceptable blank all semiconductor **Terminal Type And Quantity:** 3 screw and 4 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No